

TD-0062

SO 8



DIL 8

The devices feature high slew rate, low input bias and offset currents, and low offset voltage temperature coefficient.

- Very low power consumption.
- Wide common-mode and differential voltage ranges.
- Low input bias and offset currents.
- Typical supply current 200 μ A.
- Output short-circuit protection.
- High impedance J-FET input stage.
- Internal frequency compensation.
- Latch-up free operation.
- High slew rate 3.5 V/ μ s typ.

CHARACTERISTIC	SYMBOL	UNIT	SINGLE							DUAL				QUAD			
Supply voltage	V_{CC} max.	V	± 18	± 18	± 18	± 18	± 18	± 18	± 18	± 18	± 18	± 18	± 18	± 18	± 18	± 18	
Input offset voltage	V_{IO} max.	mV	10	15	10	10	10	10	15	10	15	10	15	10	15	10	
Input offset current	I_{IO} max.	nA	0.05	0.2	0.05	0.05	0.05	0.1	0.2	0.05	0.2	0.1	0.2	0.05	0.2	0.1	
Input impedance	Z_i typ.	$10^6 \Omega$	1	1	1	1	1	1	1	1	1	1	1	1	1	1	
Input bias current	I_{B} max.	nA	0.2	0.4	0.2	0.2	0.2	0.2	0.4	0.2	0.4	0.2	0.4	0.2	0.4	0.2	
Slew rate	S_{VO} typ.	V/ μ s	13	13	5	12	50	13	3.5	13	13	13	3.5	13	13	13	
Supply voltage rejection ratio	S_{VR} min.	dB	70	70	80	80	80	70	70	70	70	70	70	70	70	70	
Gain $\times$ bandwidth	B typ.	MHz	3	3	2.5	4.5	20	4	1	3	3	4	1	3	3	4	
Voltage gain	A_v min.	V/mV	25	25	25	25	25	25	3	25	25	25	3	25	25	25	
Input voltage range	(V_i max.) min.	V	± 11	± 10	± 10	± 10	± 10	± 11	± 10	± 11	± 10	± 11	± 10	± 11	± 10	± 11	

	TD-0071	TD-0081	TD-0155	TD-0156	TD-0157	TD-0351	TD-0682	TD-0072	TD-0082	TD-0353	TD-0084	TD-0074	TD-0084	TD-0347
Plastic SO 8-14	⑧				⑧	⑧		⑧	⑧	⑭		⑭		
Plastic DIL 8-14	⑧	⑧	⑧	⑧	⑧	⑧	⑧	⑧	⑧	⑭	⑭	⑭	⑭	
Cerdip DIL 14										●	●	●		
Chip carrier		●	●					●				●		
Metal can TO 99	●		●	●	●	●		●	●					